

PS9001

R08DS0130EJ0101

Rev.1.01

Oct 29, 2018

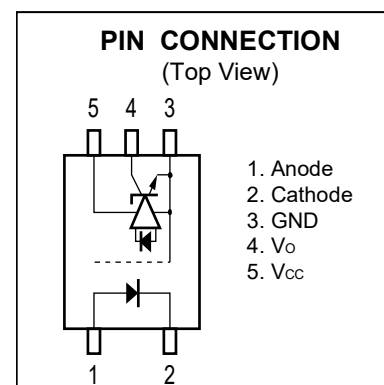
HIGH CMR, 10 Mbps OPEN COLLECTOR OUTPUT TYPE,
5-PIN SOP (LSO5 WITH 8mm CREEPAGE DISTANCE) PHOTOCOUPLER

DESCRIPTION

The PS9001 is an optically coupled high-speed, active low type isolator containing an AlGaAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

FEATURES

- Long creepage distance (8 mm MIN)
- High common mode transient immunity (CM_H , $CM_L = \pm 50 \text{ kV}/\mu\text{s}$ MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- High-speed response ($t_{PHL} = 100 \text{ ns}$ MAX., $t_{PLH} = 100 \text{ ns}$ MAX.)
- Embossed tape product : PS9001-F3: 3000 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: UL1577, Double protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Reinforced insulation
 - VDE approved: DIN EN 60747-5-5 (Option)

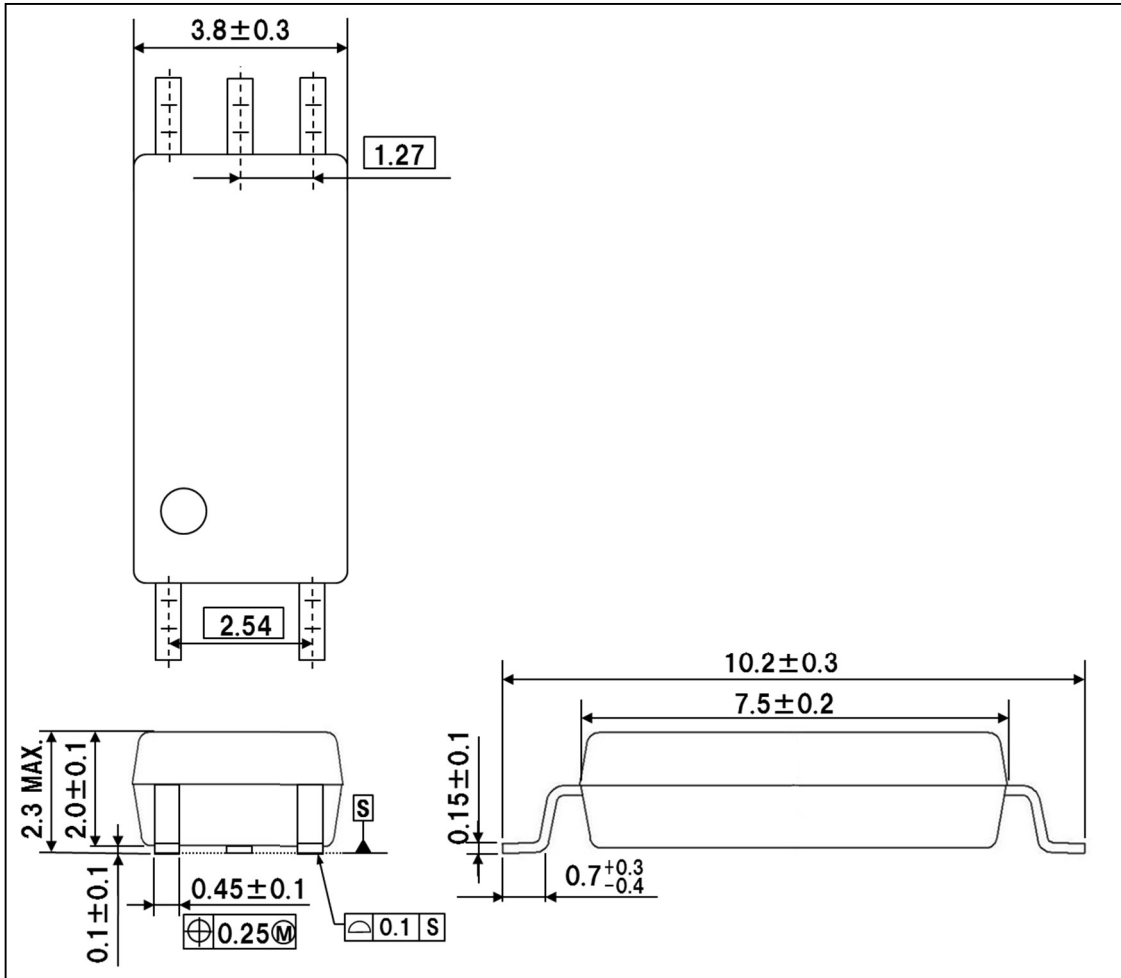


APPLICATIONS

- Measurement equipment
- FA Network

Start of mass production
Oct.2015

PACKAGE DIMENSIONS (UNIT: mm)

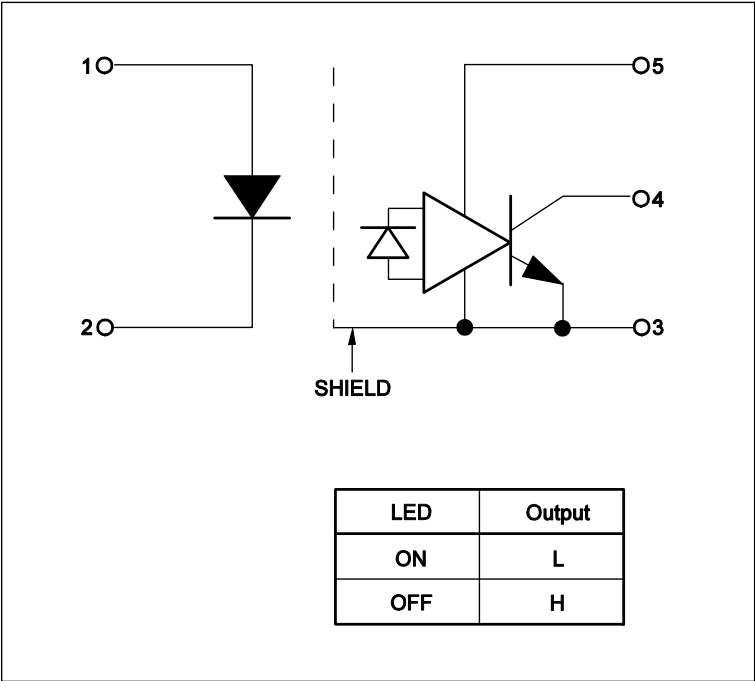


Weight : 0.119g (typ.)

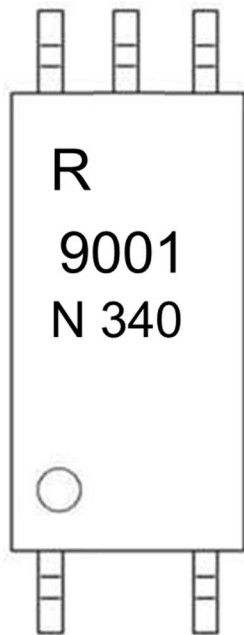
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8.0 mm
Creepage Distance	8.0 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM (Unit: mm)



MARKING EXAMPLE



R		An initial of "Renesas"	
9001		Product Part Number	
○		No.1 pin Mark, Anode Mark	
N340	N	Rank Code	
	340	Assembly Lot	
		3	Last one-digit of Assembly Year
		40	Weekly Serial Code

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9001	PS9001-Y-AX	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA approved)	PS9001
PS9001-F3	PS9001-Y-F3-AX		Embossed Tape 3 000 pcs/reel		
PS9001-V	PS9001-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5 approved	
PS9001-V-F3	PS9001-Y-V-F3-AX		Embossed Tape 3 000 pcs/reel		

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current *1	I_F	25	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V_{CC}	-0.5 to 7	V
	Output Voltage	V_O	-0.5 to 7	V
	Output Current	I_O	20	mA
	Power Dissipation	P_C	100	mW
	Isolation Voltage *2	BV	5000	Vr.m.s.
Operating Ambient Temperature		T_A	-40 to +125	$^\circ\text{C}$
Storage Temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: *1. Reduced to 0.325 mA/ $^\circ\text{C}$ at $T_A = 85^\circ\text{C}$ or more.

*2. AC voltage for 1 minute at $T_A = 25^\circ\text{C}$, RH = 60% between input and output.

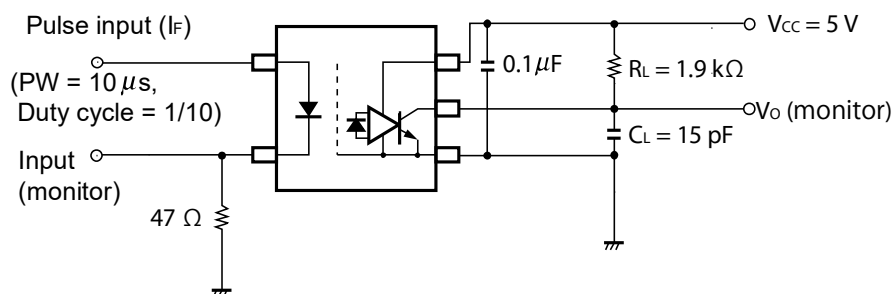
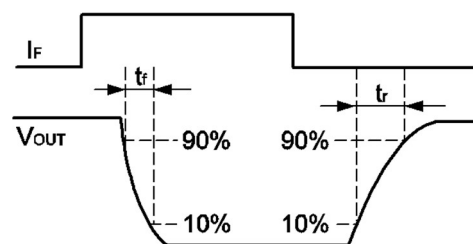
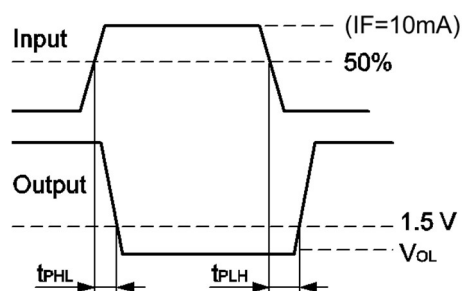
Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

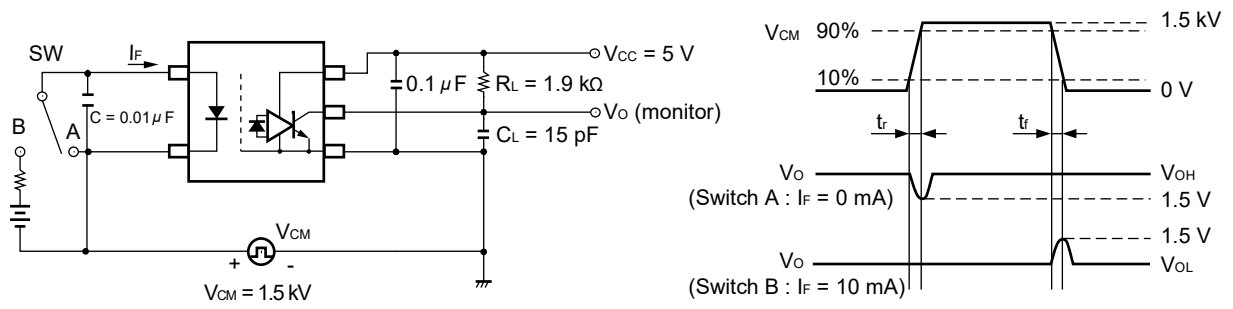
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Voltage	V_F	-2	-	0.8	V
Low Level Input Current	I_F	8	10	12	mA
Supply Voltage	V_{CC}	4.5	5.0	5.5	V
Operating Ambient Temperature	T_A	-40	-	125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = -40$ to $+125^\circ\text{C}$, $V_{CC}=5\text{V}$ unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP. *1	MAX.	Unit
Diode	Forward Voltage	V_F	$I_F = 10\text{ mA}$, $T_A = 25^\circ\text{C}$	1.35	1.56	1.75	V
	Reverse Current	I_R	$V_R = 3\text{ V}$, $T_A = 25^\circ\text{C}$			10	μA
	Terminal Capacitance	C_t	$f = 1\text{ MHz}$, $V_F = 0\text{ V}$, $T_A = 25^\circ\text{C}$		30		pF
Detector	High Level Output Current	I_{OH}	$V_{CC} = V_O = 5.5\text{ V}$, $V_F = 0.8\text{ V}$			50	μA
	Low Level Output Voltage	V_{OL}	$I_F = 4\text{ mA}$, $I_{OL} = 5\text{ mA}$		0.1	0.6	V
	High Level Supply Current	I_{CCH}	$V_{CC} = 5.5\text{ V}$, $I_F = 0\text{ mA}$, $V_O = \text{open}$		1.4	2.0	mA
	Low Level Supply Current	I_{CCL}	$V_{CC} = 5.5\text{ V}$, $I_F = 10\text{ mA}$, $V_O = \text{open}$		1.4	2.0	mA
Coupled	Threshold Input Voltage ($H \rightarrow L$)	I_{FHL}	$V_O = 0.6\text{ V}$, $I_O = 5\text{ mA}$		1.2	4.0	mA
	Propagation Delay Time ($H \rightarrow L$) *2	t_{PHL}	$I_F = 10\text{ mA}$, $R_L = 1.9\text{ k}\Omega$, $C_L = 15\text{ pF}$, $V_{THHL} = 1.5\text{ V}$, $V_{THLH} = 1.5\text{ V}$		35	100	ns
	Propagation Delay Time ($L \rightarrow H$) *2	t_{PLH}			65	100	ns
	Pulse Width Distortion (PWD)	$\begin{vmatrix} t_{PHL} \\ t_{PLH} \end{vmatrix}$			30	50	ns
	Propagation Delay Skew	t_{psk}				60	ns
	Common Mode Transient Immunity at High Level Output *3	CM_H	$T_A = 25^\circ\text{C}$, $I_F = 0\text{ mA}$, $V_O > 1.5\text{ V}$, $R_L = 1.9\text{ k}\Omega$, $V_{CM} = 1.5\text{ kV}$, $C_L = 15\text{ pF}$	50			kV/ μs
	Common Mode Transient Immunity at Low Level Output *3	CM_L	$T_A = 25^\circ\text{C}$, $I_F = 10\text{ mA}$, $V_O < 1.5\text{ V}$, $R_L = 1.9\text{ k}\Omega$, $V_{CM} = 1.5\text{ kV}$, $C_L = 15\text{ pF}$	50			kV/ μs

Notes: *1. Typical values at $T_A = 25^\circ\text{C}$ *2. Test circuit for t_{PHL} and t_{PLH} **Remark** C_L includes probe and stray wiring capacitance.

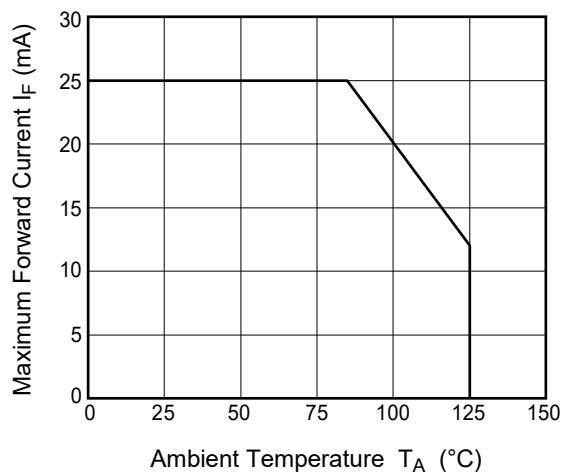
*3. Test circuit for common mode transient immunity



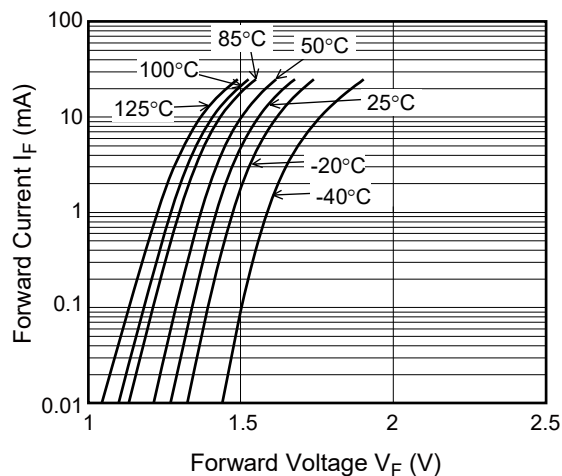
Remark C_L includes probe and stray wiring capacitance.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

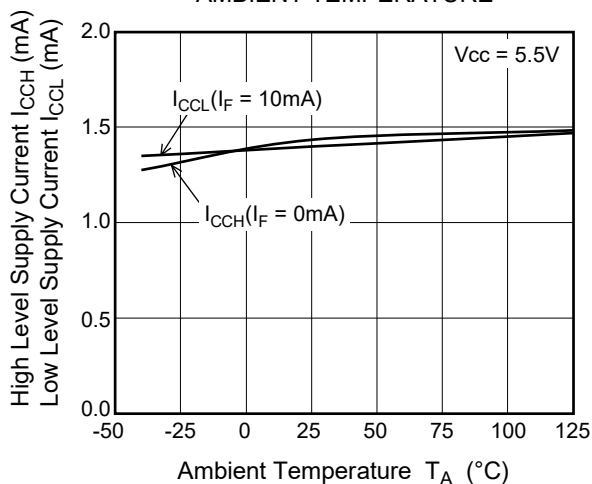
MAXIMUM FORWARD CURRENT
vs. AMBIENT TEMPERATURE



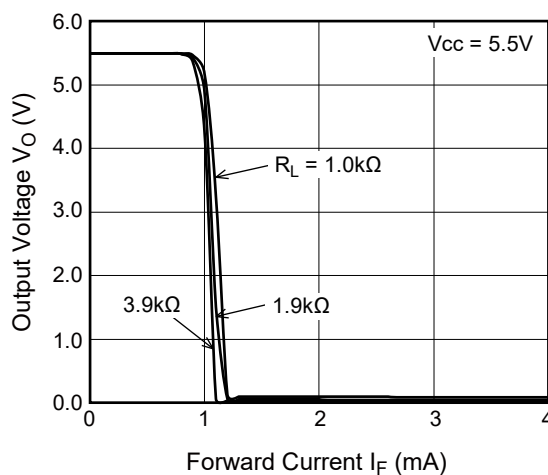
FORWARD CURRENT vs.
FORWARD VOLTAGE



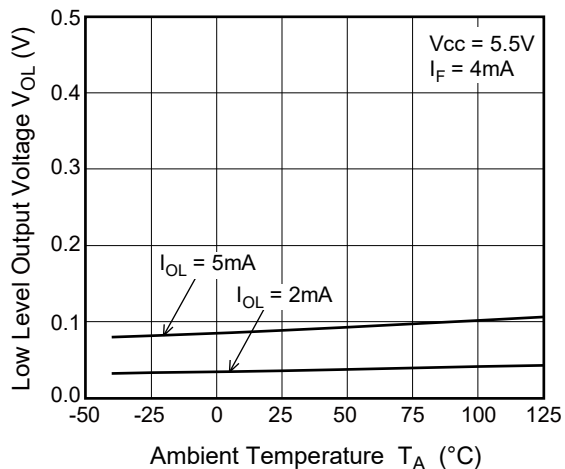
SUPPLY CURRENT vs.
AMBIENT TEMPERATURE



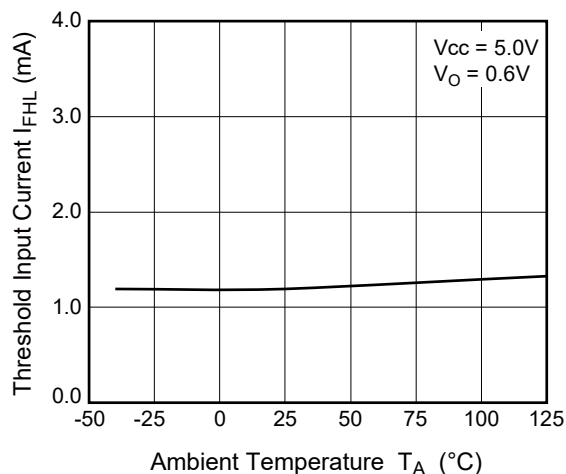
OUTPUT VOLTAGE vs.
FORWARD CURRENT



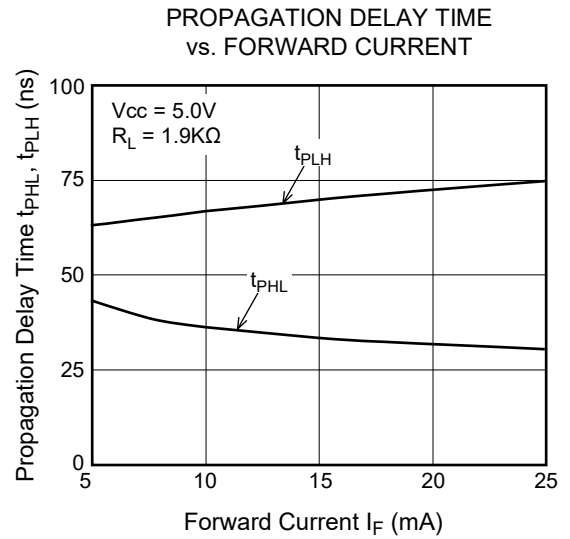
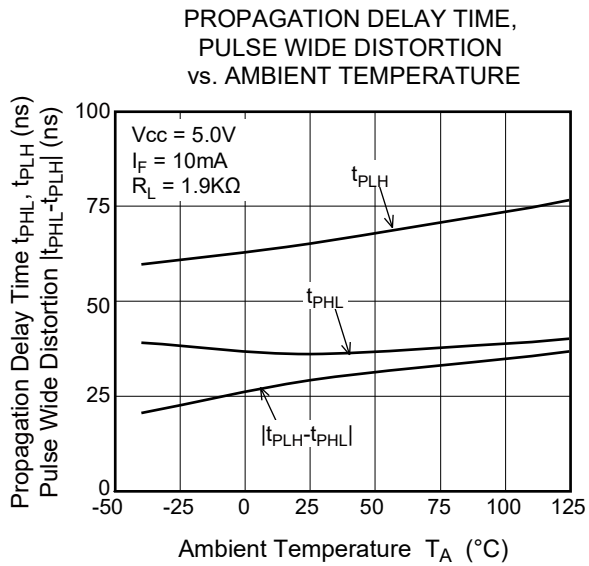
LOW LEVEL OUTPUT VOLTAGE vs.
AMBIENT TEMPERATURE



THRESHOLD INPUT CURRENT vs.
AMBIENT TEMPERATURE

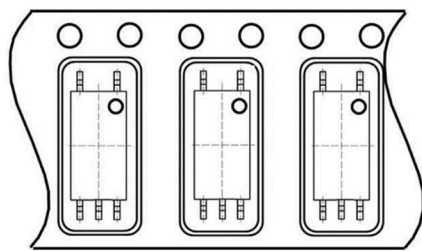


Remark The graphs indicate nominal characteristics.



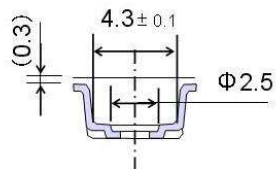
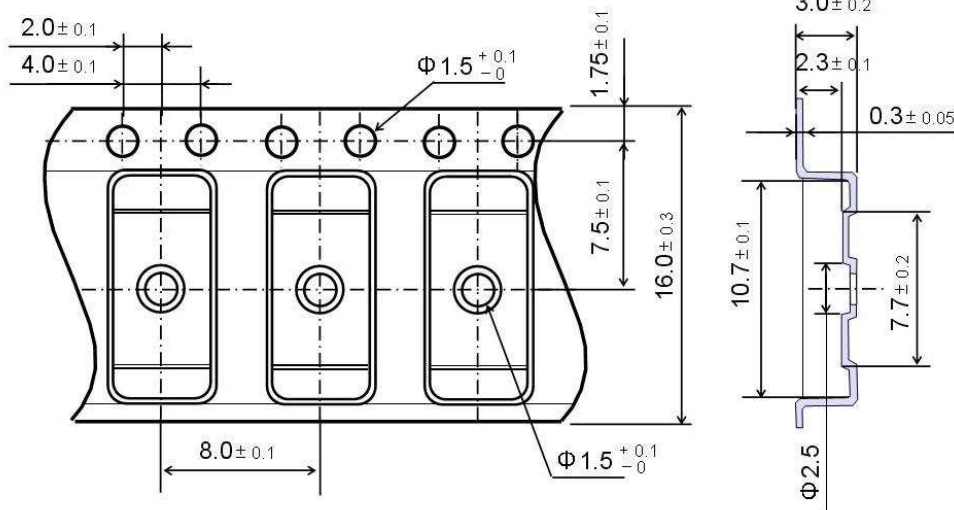
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

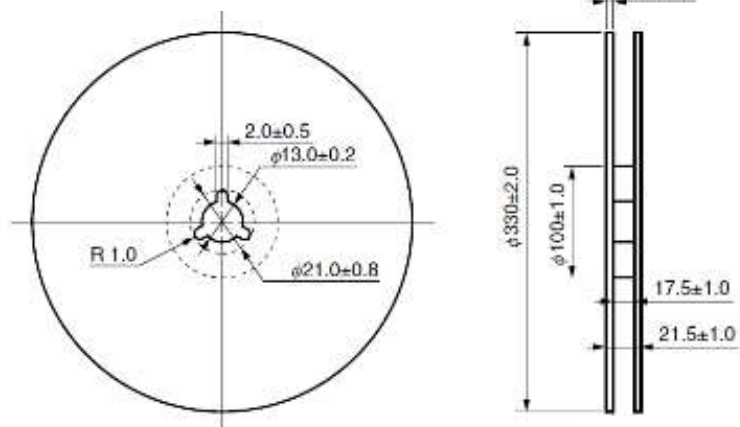


→
Tape Direction

Outline and Dimensions (Taps)

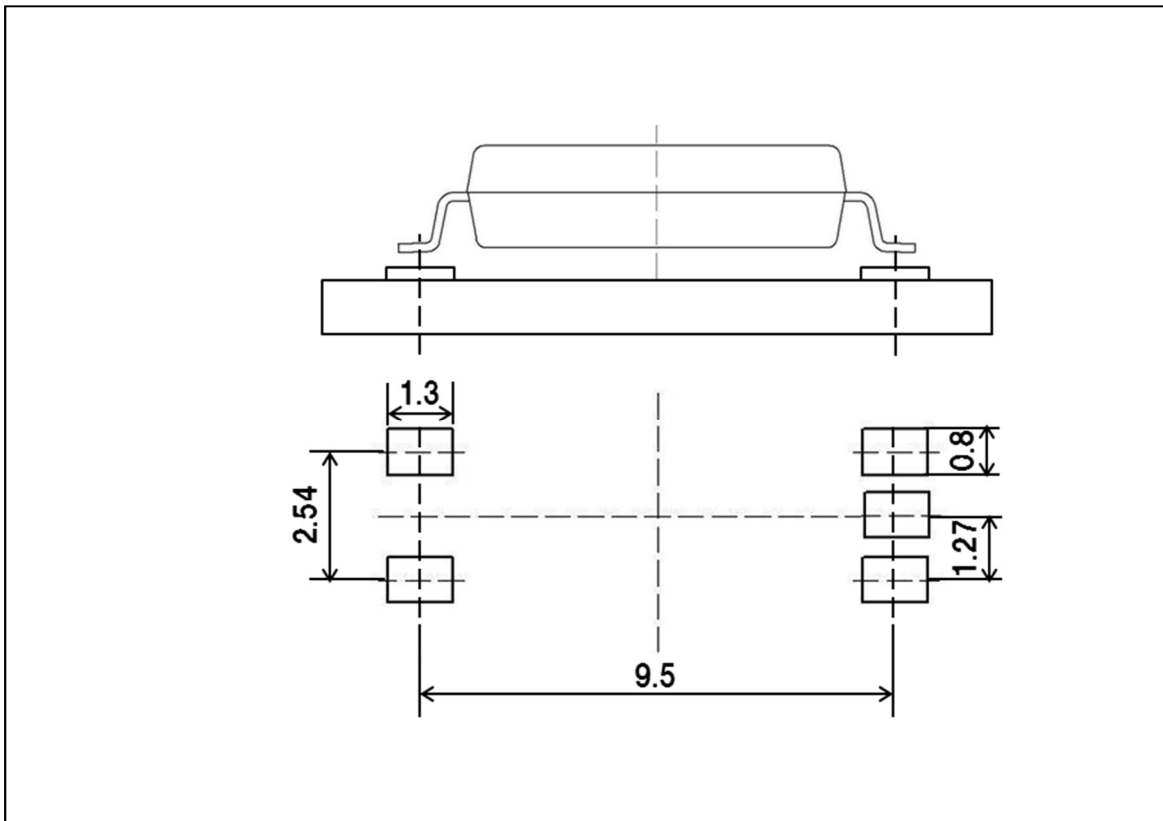


Outline and Dimensions (Reel)



Packing: 3000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

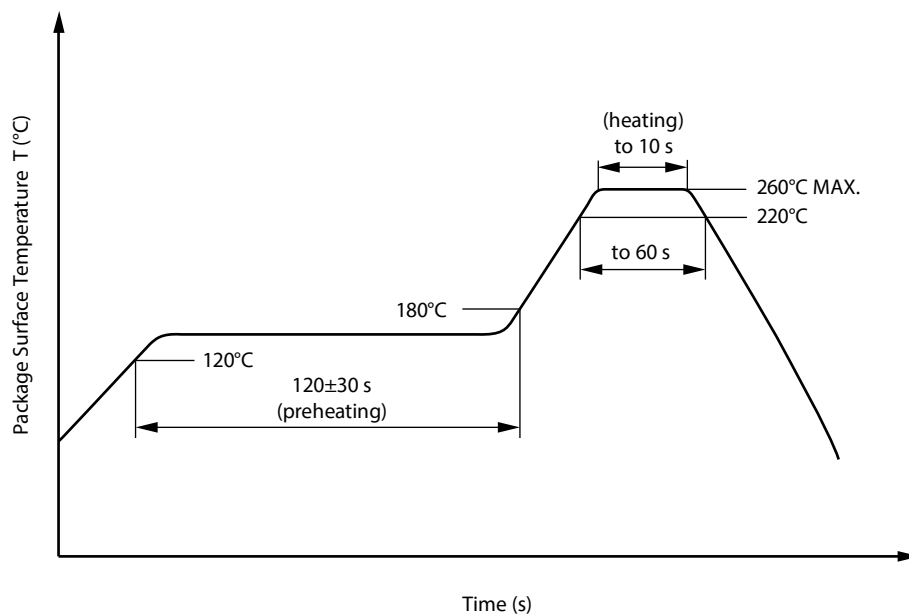
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- | | |
|---|--|
| • Peak reflow temperature | 260°C or below (package surface temperature) |
| • Time of peak reflow temperature | 10 seconds or less |
| • Time of temperature higher than 220°C | 60 seconds or less |
| • Time to preheat temperature from 120 to 180°C | 120±30 s |
| • Number of reflows | Three |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- | | |
|-------------------------|--|
| • Temperature | 260°C or below (molten solder temperature) |
| • Time | 10 seconds or less |
| • Preheating conditions | 120°C or below (package surface temperature) |
| • Number of times | One (Allowed to be dipped in solder including plastic mold portion.) |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(3) Soldering by Soldering Iron

- | | |
|--|--|
| • Peak Temperature (lead part temperature) | 350°C or below |
| • Time (each pins) | 3 seconds or less |
| • Flux | Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.) |

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

- Fluxes Avoid removing the residual flux with freon-based and halogens-based (chlorine-based) cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

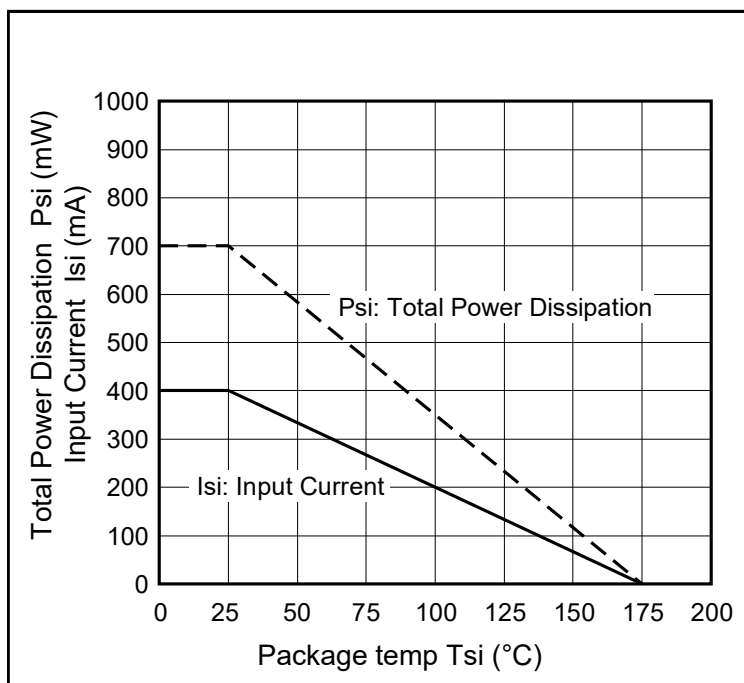
USAGE CAUTIONS

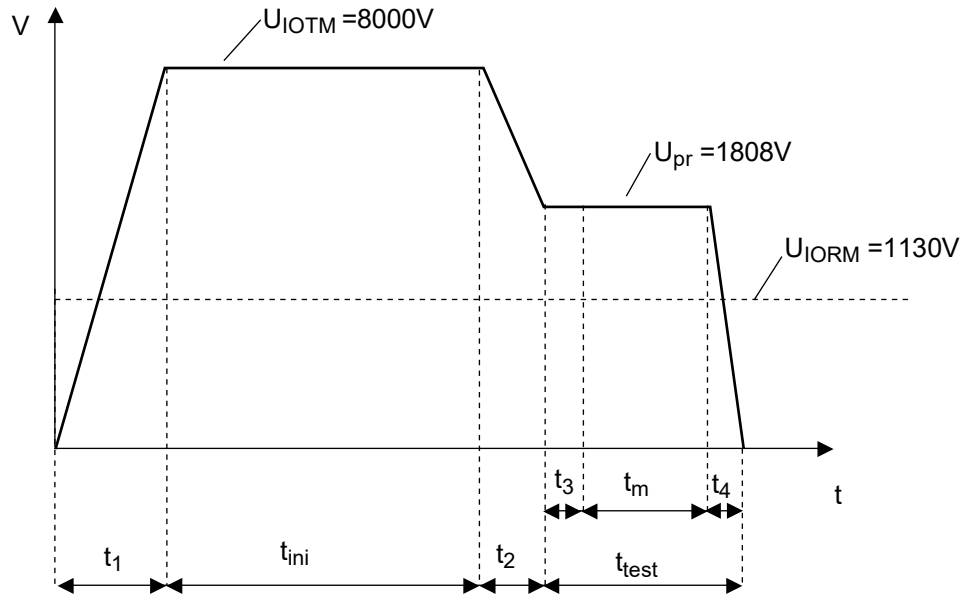
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.
4. Do not use adhesives or coating materials including halogens to fix this device.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

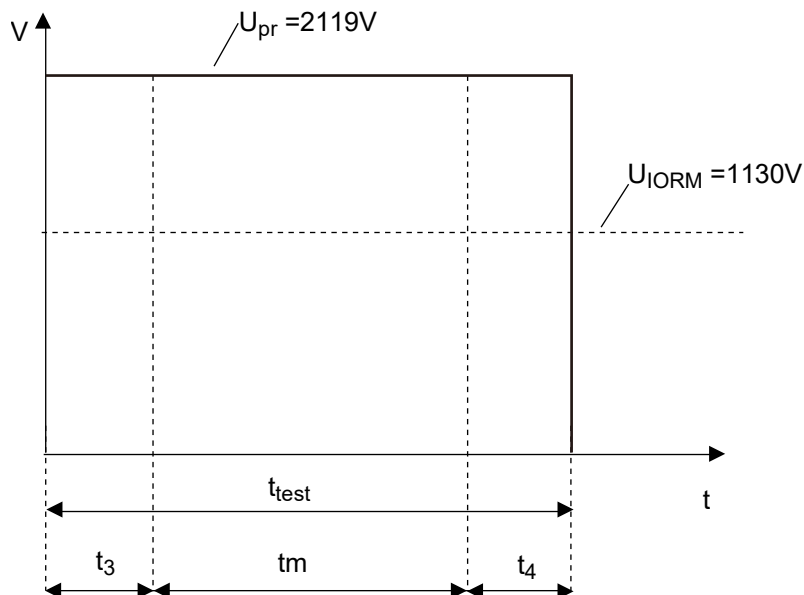
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}$, $P_d < 5 \text{ pC}$	U_{IORM} U_{pr}	1 130 1 808	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}$, $P_d < 5 \text{ pC}$	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{TR}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		II	
Storage temperature range	T_{stg}	-55 to +150	°C
Operating temperature range	T_A	-40 to +125	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^\circ\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^\circ\text{C}$	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $P_{si} = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = T_{si}$	T_{si} I_{si} P_{si} Ris MIN.	175 400 700 10^9	°C mA mW Ω

Dependence of maximum safety ratings with package temperature



Method a) Destructive Test, Type and Sample Test

$t_1, t_2 = 1 \text{ to } 10 \text{ sec}$
 $t_3, t_4 = 1 \text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 10 \text{ sec}$
 $t_{test} = 12 \text{ sec}$
 $t_{ini} = 60 \text{ sec}$

Method b) Non-destructive Test, 100% Production Test

$t_3, t_4 = 0.1 \text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 1.0 \text{ sec}$
 $t_{test} = 1.2 \text{ sec}$

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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(Rev.4.0-1 November 2017)



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